DUSEU

MARKING

TinyLogic UHS 2-Input **Non-Inverting Multiplexer**

NC7SZ157

Description

The NC7SZ157 is a single, high performance, 2-to-1 CMOS non-inverting multiplexer from onsemi's Ultra-High Speed series of TinyLogic. The device is fabricated with advanced CMOS technology to achieve ultra high speed with high output drive while maintaining low static power dissipation over a broad V_{CC} operating range. The device is specified to operate over the 1.65 V to 5.5 V V_{CC} operating range. The inputs and outputs are high impedance when V_{CC} is 0 V. Inputs tolerate voltages up to 5.5 V independent of V_{CC} operating range.

Features

- Broad V_{CC} Operating Range: 1.65 V to 5.5 V
- Ultra High-Speed
- Power Down High–Impedance Inputs / Outputs
- Over-Voltage Tolerance Inputs Facilitate 5 V to 3 V Translation
- Proprietary Noise / EMI Reduction Circuitry
- Ultra-Small MicroPakTM Packages
- Space–Saving SC–88 Package
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

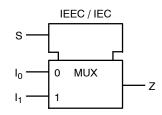
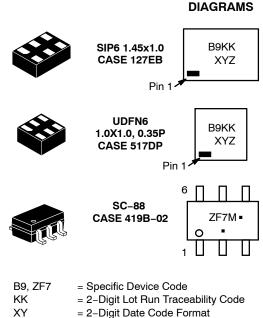


Figure 1. Logic Symbol



- = 2-Digit Date Code Format
- = Assembly Plant Code
- = Date Code*

Ζ

М

= Pb-Free Package

(Note: Microdot may be in either location)

*Date Code orientation and/or position may vary depending upon manufacturing location.

ORDERING INFORMATION

See detailed ordering, marking and shipping information in the package dimensions section on page 6 of this data sheet.

Pin Configurations

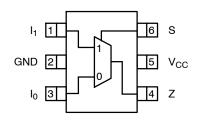
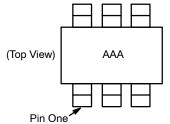


Figure 2. SC-88 (Top View)



NOTES:

- AAA represents product code top mark (*see Ordering Information*).
 Orientation of top mark determines pin one location.
 Reading the top mark left to right, pin one is the lower left pin.

Figure 4. Pin 1 Orientation

PIN DEFINITIONS

Pin # SC-88	Pin # MicroPak	Name	Description
1	1	l ₁	Data Input
2	2	GND	Ground
3	3	I ₀	Data Input
4	4	Z	Output
5	5	V _{CC}	Supply Voltage
6	6	S	Control Input

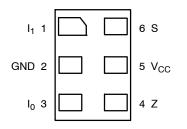


Figure 3. MicroPak (Top Through View)

FUNCTION TABLE

Inputs			Output
S	I ₁	I ₀	$Z = (I_0) \cdot (\overline{S}) + (I_1) \cdot (S)$
L	Х	L	L
L	Х	Н	Н
Н	L	Х	L
Н	Н	Х	Н

H = HIGH Logic Level L = LOW Logic Level X = Don't Care

ABSOLUTE MAXIMUM RATINGS

Symbol	Param	Min	Max	Unit	
V _{CC}	Supply Voltage	-0.5	6.5	V	
V _{IN}	DC Input Voltage		-0.5	6.5	V
V _{OUT}	DC Output Voltage		-0.5	6.5	V
I _{IK}	DC Input Diode Current	V _{IN} < 0 V	-	-50	mA
I _{OK}	DC Output Diode Current	V _{OUT} < 0 V	-	-50	mA
I _{OUT}	DC Output Current	-	±50	mA	
$I_{CC} \text{ or } I_{GND}$	DC V _{CC} or Ground Current	-	±50	mA	
T _{STG}	Storage Temperature Range	-65	+150	°C	
TJ	Junction Temperature Under Bias		-	+150	°C
ΤL	Junction Lead Temperature (Sold	ering, 10 Seconds)	-	+260	°C
PD	Power Dissipation in Still Air	SC-88	-	332	mW
	MicroPak-6		-	812	
		MicroPak2™–6	-	812	
ESD	ESD Human Body Model, JEDEC: JESD22-A114		-	4000	V
	Charge Device Model, JEDEC: J	ESD22-C101	-	2000	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Conditions	Min	Мах	Unit
V _{CC}	Supply Voltage Operating		1.65	5.5	V
	Supply Voltage Data Retention		1.50	5.5	
V _{IN}	Input Voltage		0	5.5	V
V _{OUT}	Output Voltage		0	V _{CC}	V
T _A	Operating Temperature		-40	+85	°C
t _r , t _f	Input Rise and Fall Times	V_{CC} at 1.8 V ± 0.15 V, 2.5 V ± 0.2 V	0	20	ns/V
		V_{CC} at 3.3 V ± 0.3 V	0	10	
		V_{CC} at 5.0 V ± 0.5 V	0	5	
θ_{JA}	Thermal Resistance	SC-88	_	377	°C/W
		MicroPak-6	_	154	
		MicroPak2-6	_	154	°C/W

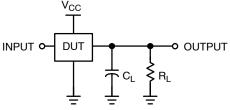
Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

DC ELECTRICAL CHARACTERISTICS

					T,	a = +25°	°C	T _A = −40 to +85°C			
Symbol	Parameter	V _{CC} (V)	c	onditions	Min	Тур	Max	Min	Max	Unit	
VIH	HIGH Level	1.65 to 1.95			$0.65 V_{CC}$	-	-	0.65 V _{CC}	-	V	
	Input Voltage	2.30 to 5.50			$0.70 V_{CC}$	-	-	0.70 V _{CC}	-		
V _{IL}	LOW Level	1.65 to 1.95			-	-	0.35 V _{CC}	_	0.35 V _{CC}	V	
	Input Voltage	2.30 to 5.50			-	-	0.30 V _{CC}	-	0.30 V _{CC}		
V _{OH}	HIGH Level	1.65	$V_{IN} = V_{IH}$	I _{OH} = -100 μA	1.55	1.65	-	1.55	-	V	
	Output Voltage	2.30	or V _{IL}		2.20	2.30	-	2.20	-		
		3.00			2.90	3.00	-	2.90	-		
		4.50			4.40	4.50	-	4.40	-		
		1.65		I _{OH} = -4 mA	1.29	1.52	-	1.29	-		
		2.30		I _{OH} = -8 mA	1.90	2.15	-	1.90	-		
		3.00		I _{OH} = -16 mA	2.40	2.80	-	2.40	-		
		3.00		I _{OH} = -24 mA	2.30	3.68	-	2.30	-		
		4.50				I _{OH} = -32 mA	3.90	4.20	-	3.80	-
V _{OL}	LOW Level Output Voltage	1.65	V _{IN} = V _{IH}	I _{OL} = 100 μA	-	0	0.10	-	0.10	V	
		2.30 or V _{IL}		-	0	0.10	-	0.10			
		3.00				-	0	0.10	-	0.10	
		4.50			-	0	0.10	-	0.10		
		1.65	1	I _{OL} = 4 mA	-	0.08	0.24	-	0.24		
		2.30	1	I _{OL} = 8 mA	-	0.10	0.30	-	0.30		
		3.00	1	I _{OL} = 16 mA	-	0.15	0.40	-	0.40		
		3.00		I _{OL} = 24 mA	-	0.22	0.55	-	0.55		
		4.50	1	I _{OL} = 32 mA	-	0.22	0.55	-	0.55		
I _{IN}	Input Leakage Current	1.65 to 5.5		V _{IN} = 5.5 V, GND	-	_	±0.1	-	±1	μA	
I _{OFF}	Power Off Leakage Current	0		V _{IN} or V _{OUT} = 5.5 V	-	_	1.0	-	10	μA	
I _{CC}	Quiescent Supply Current	1.65 to 5.50		V _{IN} = 5.5 V, GND	-	-	1.0	_	10	μA	

				T _A = +25°C		T _A = -40	to +85°C		
Symbol	Parameter	V _{CC} (V)	Conditions	Min	Тур	Max	Min	Max	Unit
t _{PLH} , t _{PHL}	Propagation Delay S to Z (Figure 5, 6)	1.80 ±0.15	$C_{L} = 15 pF$,	-	6.0	11.5	-	12.0	ns
	(Figure 5, 6)	2.50 ±0.20	R _L = 1 MΩ,	-	3.5	6.1	-	6.5	
		3.30 ±0.30		-	2.6	4.1	-	4.5	
		5.00 ±0.50		-	1.9	3.2	-	3.5	
	Propagation Delay I _n to Z	1.80 ±0.15	$C_{L} = 15 \text{ pF},$	-	5.9	10.0	-	10.5	
	(Figure 5, 6)	5.00 ±0.50	R _L = 1MΩ,	-	3.5	5.8	-	6.1	
		3.30 ±0.30		-	2.6	3.9	-	4.2	
		5.00 ±0.50		-	1.9	3.1	-	3.3	
	Propagation Delay S to Z	3.30 ±0.30	$C_{L} = 50 \text{ pF},$	-	3.2	4.8	-	5.2	
	(Figure 5, 6)	5.00 ±0.50	R _L = 500 Ω,	-	2.4	3.8	-	4.1	
	Propagation Delay In to Z	3.30 ±0.30	$C_{L} = 50 \text{ pF},$	-	3.2	4.6	-	5.0	
	(Figure 5, 6)	5.00 ±0.50	R _L = 500 Ω,	-	2.4	3.7	-	4.0	
C _{IN}	Input Capacitance	0.00		-	2	-	-	_	pF
	Power Dissipation Capacitance	3.30		-	14	-	-	_	pF
	(Note 4) (Figure 7)		1	-	17	-	-	-	

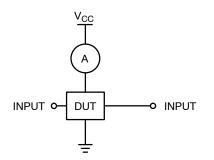
4. C_{PD} is defined as the value of the internal equivalent capacitance which is derived from dynamic operating current consumption (I_{CCD}) at no output loading and operating at 50% duty cycle. C_{PD} is related to I_{CCD} dynamic operating current by the expression: I_{CCD} = (C_{PD}) (V_{CC}) (f_{IN}) + (I_{CC}static).



NOTE:

5. CL includes load and stray capacitance; inputs PRR = 1.0 MHz, t_W = 500 ns.

Figure 5. AC Test Circuit



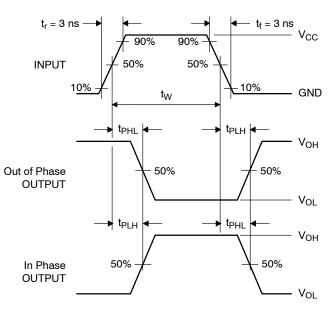
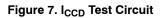


Figure 6. AC Waveforms

NOTE:

6. Input = AC Waveform; PRR = Variable; Duty Cycle = 50%.



NC7SZ157

DEVICE ORDERING INFORMATION

Device Top Mark		Packages	Shipping [†]		
NC7SZ157P6X	ZF7	6-Lead SC70, EIAJ SC-88, 1.25 mm Wide	3000 / Tape & Reel		
NC7SZ157P6X-L22347	ZF7	6-Lead SC70, EIAJ SC-88, 1.25 mm Wide	3000 / Tape & Reel		
NC7SZ157L6X	В9	6-Lead MicroPak, 1.00 mm Wide	5000 / Tape & Reel		
NC7SZ157L6X-L22175	В9	6-Lead MicroPak, 1.00 mm Wide	5000 / Tape & Reel		
NC7SZ157FHX	В9	6-Lead, MicroPak2, 1x1 mm Body, .35 mm Pitch	5000 / Tape & Reel		
NC7SZ157FHX-L22175	В9	6-Lead, MicroPak2, 1x1 mm Body, .35 mm Pitch	5000 / Tape & Reel		

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MicroPak and MicroPak2 are trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries.



SIP6 1.45X1.0 CASE 127EB ISSUE O

DATE 31 AUG 2016



0.043

0.004





- XXX = Specific Device Code

(Note: Microdot may be in either location)

*Date Code orientation and/or position may vary depending upon manufacturing location.

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.



DIMENSIONS: MILLIMETERS

*For additional information on our Pb-Free strategy and soldering

details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

Electronic versions are uncontrolled except when accessed directly from the Document Repository. DOCUMENT NUMBER: 98ASB42985B Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red. **DESCRIPTION:** SC-88/SC70-6/SOT-363 PAGE 1 OF 2 ON Semiconductor and unarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.

SC-88/SC70-6/SOT-363 CASE 419B-02 ISSUE Y

DATE 11 DEC 2012

STYLE 1: PIN 1. EMITTER 2 2. BASE 2 3. COLLECTOR 1 4. EMITTER 1 5. BASE 1 6. COLLECTOR 2	STYLE 2: CANCELLED	STYLE 3: CANCELLED	STYLE 4: PIN 1. CATHODE 2. CATHODE 3. COLLECTOR 4. EMITTER 5. BASE 6. ANODE	STYLE 5: PIN 1. ANODE 2. ANODE 3. COLLECTOR 4. EMITTER 5. BASE 6. CATHODE	STYLE 6: PIN 1. ANODE 2 2. N/C 3. CATHODE 1 4. ANODE 1 5. N/C 6. CATHODE 2
STYLE 7: PIN 1. SOURCE 2 2. DRAIN 2 3. GATE 1 4. SOURCE 1 5. DRAIN 1 6. GATE 2	STYLE 8: CANCELLED	STYLE 9: PIN 1. EMITTER 2 2. EMITTER 1 3. COLLECTOR 1 4. BASE 1 5. BASE 2 6. COLLECTOR 2	STYLE 10: PIN 1. SOURCE 2 2. SOURCE 1 3. GATE 1 4. DRAIN 1 5. DRAIN 2 6. GATE 2	STYLE 11: PIN 1. CATHODE 2 2. CATHODE 2 3. ANODE 1 4. CATHODE 1 5. CATHODE 1 6. ANODE 2	STYLE 12: PIN 1. ANODE 2 2. ANODE 2 3. CATHODE 1 4. ANODE 1 5. ANODE 1 6. CATHODE 2
STYLE 13:	STYLE 14:	STYLE 15:	STYLE 16:	STYLE 17:	STYLE 18:
PIN 1. ANODE	PIN 1. VREF	PIN 1. ANODE 1	PIN 1. BASE 1	PIN 1. BASE 1	PIN 1. VIN1
2. N/C	2. GND	2. ANODE 2	2. EMITTER 2	2. EMITTER 1	2. VCC
3. COLLECTOR	3. GND	3. ANODE 3	3. COLLECTOR 2	3. COLLECTOR 2	3. VOUT2
4. EMITTER	4. IOUT	4. CATHODE 3	4. BASE 2	4. BASE 2	4. VIN2
5. BASE	5. VEN	5. CATHODE 2	5. EMITTER 1	5. EMITTER 2	5. GND
6. CATHODE	6. VCC	6. CATHODE 1	6. COLLECTOR 1	6. COLLECTOR 1	6. VOUT1
STYLE 19:	STYLE 20:	STYLE 21:	STYLE 22:	STYLE 23:	STYLE 24:
PIN 1. I OUT	PIN 1. COLLECTOR	PIN 1. ANODE 1	PIN 1. D1 (i)	PIN 1. Vn	PIN 1. CATHODE
2. GND	2. COLLECTOR	2. N/C	2. GND	2. CH1	2. ANODE
3. GND	3. BASE	3. ANODE 2	3. D2 (i)	3. Vp	3. CATHODE
4. V CC	4. EMITTER	4. CATHODE 2	4. D2 (c)	4. N/C	4. CATHODE
5. V EN	5. COLLECTOR	5. N/C	5. VBUS	5. CH2	5. CATHODE
6. V REF	6. COLLECTOR	6. CATHODE 1	6. D1 (c)	6. N/C	6. CATHODE
STYLE 25:	STYLE 26:	STYLE 27:	STYLE 28:	STYLE 29:	STYLE 30:
PIN 1. BASE 1	PIN 1. SOURCE 1	PIN 1. BASE 2	PIN 1. DRAIN	PIN 1. ANODE	PIN 1. SOURCE 1
2. CATHODE	2. GATE 1	2. BASE 1	2. DRAIN	2. ANODE	2. DRAIN 2
3. COLLECTOR 2	3. DRAIN 2	3. COLLECTOR 1	3. GATE	3. COLLECTOR	3. DRAIN 2
4. BASE 2	4. SOURCE 2	4. EMITTER 1	4. SOURCE	4. EMITTER	4. SOURCE 2
5. EMITTER	5. GATE 2	5. EMITTER 2	5. DRAIN	5. BASE/ANODE	5. GATE 1
6. COLLECTOR 1	6. DRAIN 1	6. COLLECTOR 2	6. DRAIN	6. CATHODE	6. DRAIN 1

Note: Please refer to datasheet for style callout. If style type is not called out in the datasheet refer to the device datasheet pinout or pin assignment.

DOCUMENT NUMBER:	98ASB42985B	98ASB42985B Electronic versions are uncontrolled except when accessed directly from the Document Repositor Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.					
DESCRIPTION:	SC-88/SC70-6/SOT-363		PAGE 2 OF 2				
ON Semiconductor and 💵 are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding							

ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.





ON Semiconductor and unarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights or the rights of others.

onsemi, ONSEMI, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does **onsemi** assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using **onsemi** products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by **onsemi**. "Typical" parameters which may be provided in **onsemi** data sheets and/or specifications can and do vary in different applications and calcular performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. **onsemi** does not convey any license under any of its intellectual property rights nor the rights of others. **onsemi** products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use **onsemi** products for any such unintended or unauthorized application, Buyer shall indemnify and hold **onsemi** and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that **onsemi** was negligent regarding the design or manufacture of the part. **onsemi** is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

TECHNICAL SUPPORT

onsemi Website: www.onsemi.com

Email Requests to: orderlit@onsemi.com

North American Technical Support: Voice Mail: 1 800-282-9855 Toll Free USA/Canada Phone: 011 421 33 790 2910

Europe, Middle East and Africa Technical Support: Phone: 00421 33 790 2910 For additional information, please contact your local Sales Representative